100V NPN MEDIUM POWER TRANSISTOR IN TO252

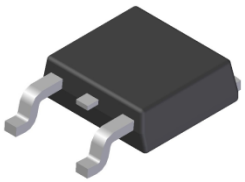
Features

- BV_{CEO} > 100V
- I_C = 6A Continuous Collector Current
- I_{CM} = 10A Peak Pulse Current
- Ideal for Power Switching or Amplification Applications
- Complementary PNP Type: MJD42CQ
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **The MJD41CQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF16949 certified facilities.**
  https://www.diodes.com/quality/product-definitions/

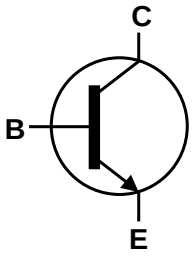
Mechanical Data

- Package: TO252 (DPAK)
- Package Material: Molded Plastic, "Green" Molding Compound UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 e3
- Weight: 0.34 grams (Approximate)

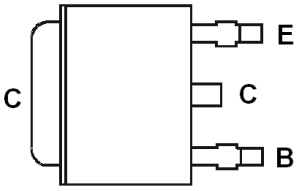
TO252 (DPAK)



Top View



Device Schematic



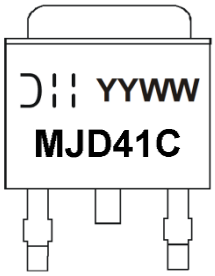
Pin Out Configuration
Top View

Ordering Information (Note 4)

Orderable Part Number	Package	Marking	Reel size (inches)	Tape width (mm)	Packing	
					Qty.	Carrier
MJD41CQ-13	TO252 (DPAK)	MJD41C	13	16	2,500	Reel

Notes:
1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



MJD41C = Product Type Marking Code
= Manufacturers' Code Marking
YYWW = Date Code Marking
YY = Last Digit of Year (ex: 23 = 2023)
WW = Week Code (01 – 53)

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	120	V
Collector-Emitter Voltage	V_{CEO}	100	V
Emitter-Base Voltage	V_{EBO}	7	V
Continuous Collector Current	I_C	6	A
Peak Pulse Collector Current	I_{CM}	10	A
Continuous Base Current	I_B	2	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Power Dissipation	(Note 5)	P_D	2.7	W
	(Note 6)		2.4	
	(Note 7)		1.5	
Thermal Resistance, Junction to Ambient Air	(Note 5)	$R_{\theta JA}$	46	°C/W
	(Note 6)		52	
	(Note 7)		83	
Operating and Storage Temperature Range		T_J, T_{STG}	-55 to +150	°C

ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

Notes:
5. For a device mounted with the exposed collector pad on 25mm x 25mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
6. Same as note (5), except mounted on 25mm x 25mm 1oz copper.
7. Same as note (5), except mounted on minimum recommended pad (MRP) layout.
8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

Thermal Characteristics

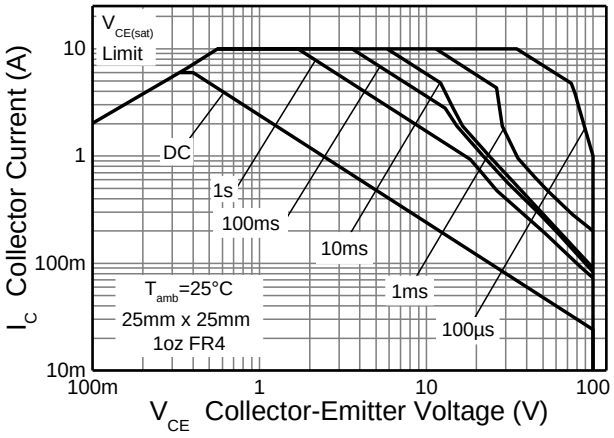


Figure 1. Safe Operating Area

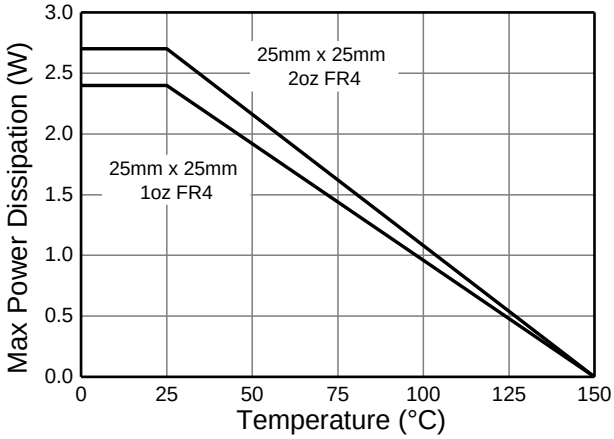


Figure 2. Derating Curve

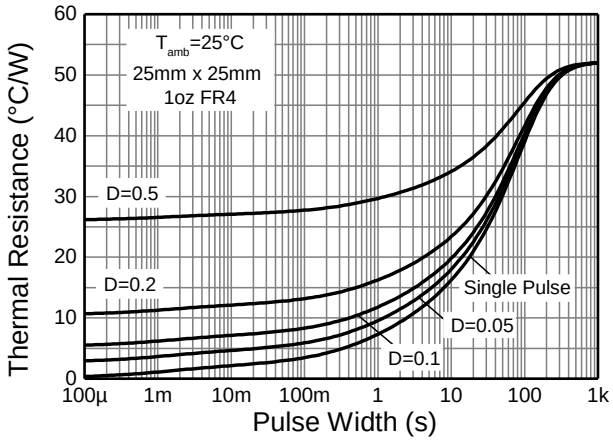


Figure 3. Transient Thermal Impedance

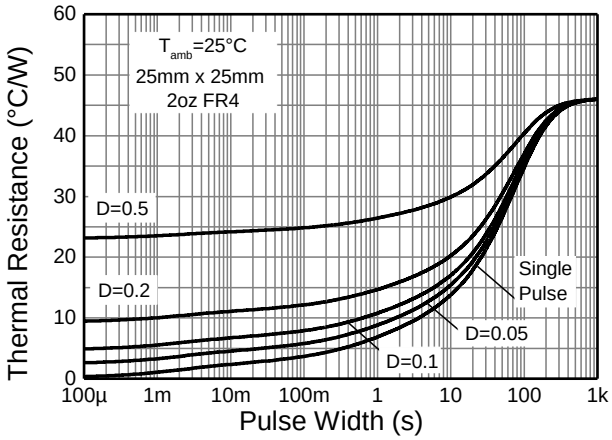


Figure 4. Transient Thermal Impedance

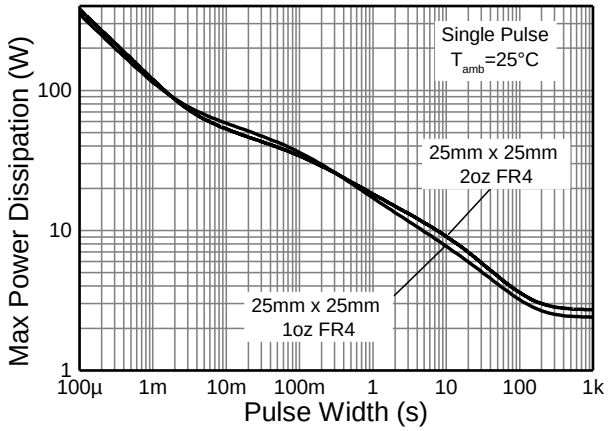


Figure 5. Pulse Power Dissipation

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV_{CBO}	120	—	—	V	I_C = 100uA
Collector-Emitter Breakdown Voltage (Note 9)	BV_{CEO}	100	—	—	V	I_C = 10mA
Emitter-Base Breakdown Voltage	BV_{EBO}	7	—	—	V	I_E = 100uA
Collector Cut-off Current	I_{CES}	—	—	1	uA	V_{CE} = 100V
Collector-Base Cut-off Current	I_{CBO}	—	—	100	nA	V_{CB} = 100V
Emitter Cut-off Current	I_{EBO}	—	—	1	uA	V_{EB} = 6V
Collector-Emitter Saturation Voltage (Note 9)	$V_{CE(sat)}$	—	—	1.5	V	I_C = 6A, I_B = 600mA
Base-Emitter Saturation Voltage (Note 9)	$V_{BE(sat)}$	—	—	1.4	V	I_C = 6A, I_B = 600mA
Base-Emitter Turn-On Voltage (Note 9)	$V_{BE(on)}$	—	—	2	V	I_C = 6A, V_{CE} = 4V
DC Current Gain (Note 9)	h_{FE}	30 15	— —	— ---	—	V_{CE} = 4V, I_C = 0.3A V_{CE} = 4V, I_C = 3A
Small Signal Current Gain	h_{fe}	20	—	—	—	V_{CE} = 10V, I_C = 0.5A, f = 1kHz
Current Gain-Bandwidth Product	f_T	3	—	—	MHz	V_{CE} = 10V, I_C = 0.5A, f = 100MHz
Output Capacitance	C_{obo}	—	42	—	pF	V_{CB} = 10V, f = 1MHz
Input Capacitance	C_{ibo}	—	91	—	pF	V_{EB} = 0.5V, f = 1MHz
Delay Time	t_d	—	46	—	ns	I_C = 1A, V_{CC} = 10V I_{B1} = -I_{B2} = 100mA
Rise Time	t_r	—	41	—	ns	
Storage Time	t_s	—	496	—	ns	
Fall Time	t_f	—	64	—	ns	

Note: 9. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.

Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

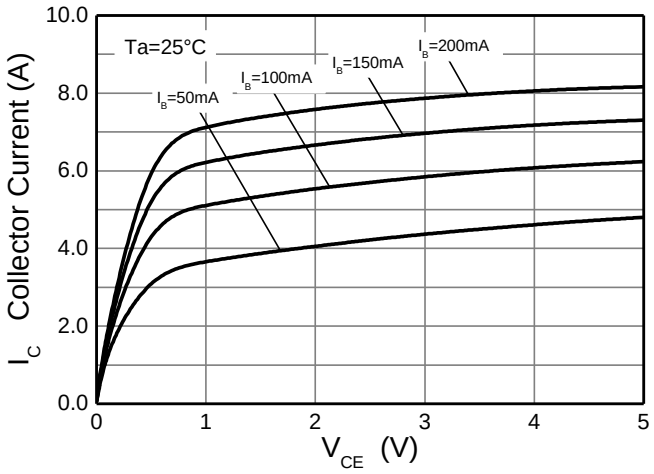


Figure 6. I_C v V_{CE}

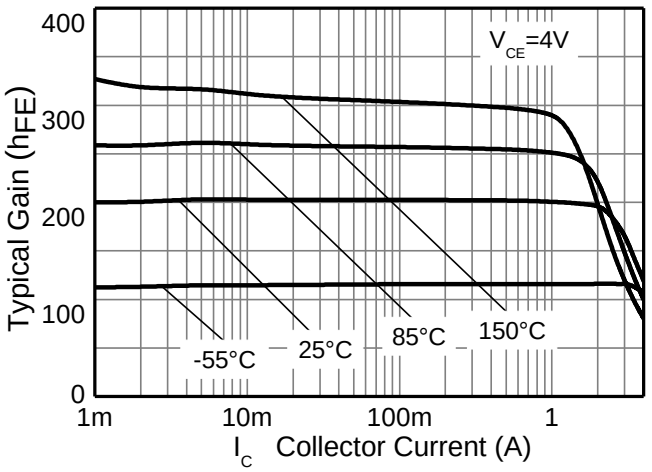


Figure 7. h_{FE} v I_C

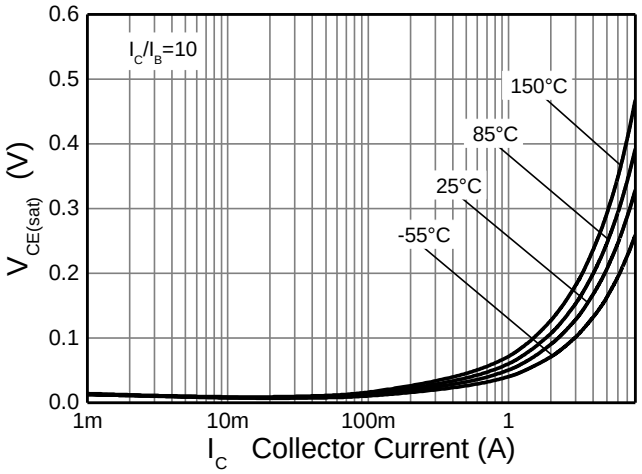


Figure 8. $V_{CE(sat)}$ v I_C

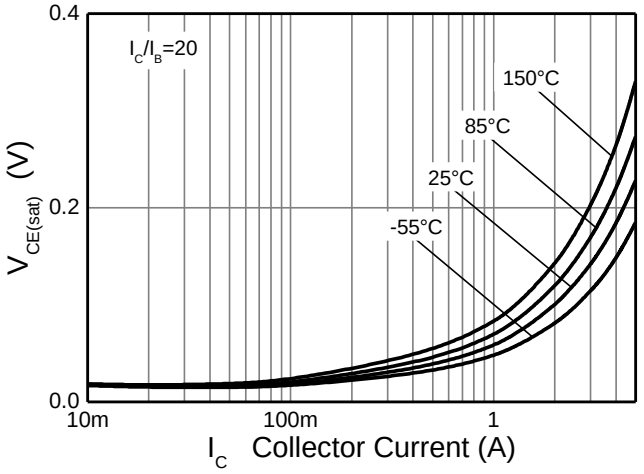


Figure 9. $V_{CE(sat)}$ v I_C

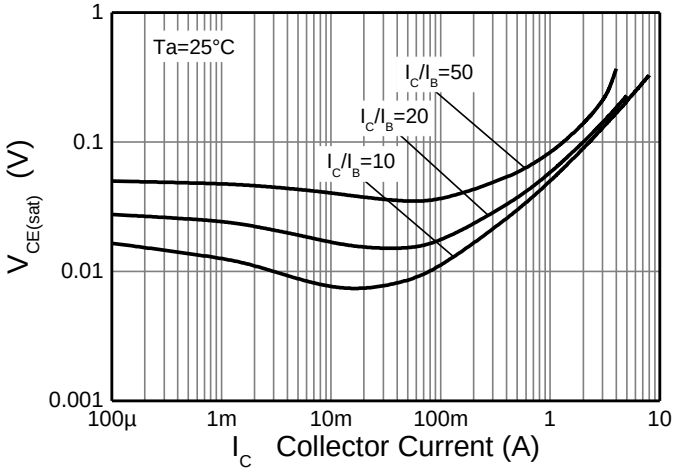


Figure 10. $V_{CE(sat)}$ v I_C

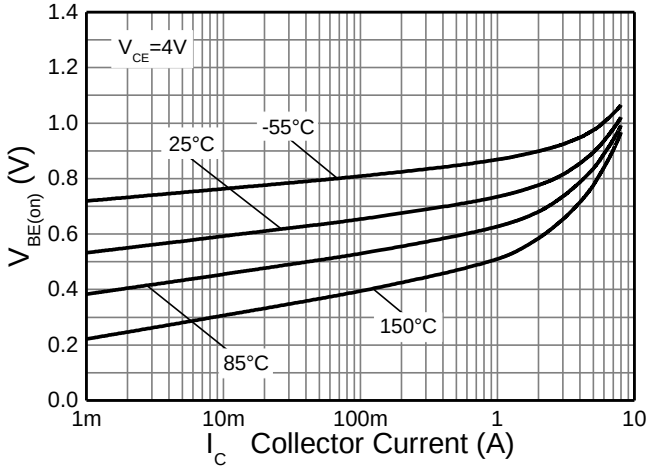


Figure 11. $V_{BE(on)}$ v I_C

Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

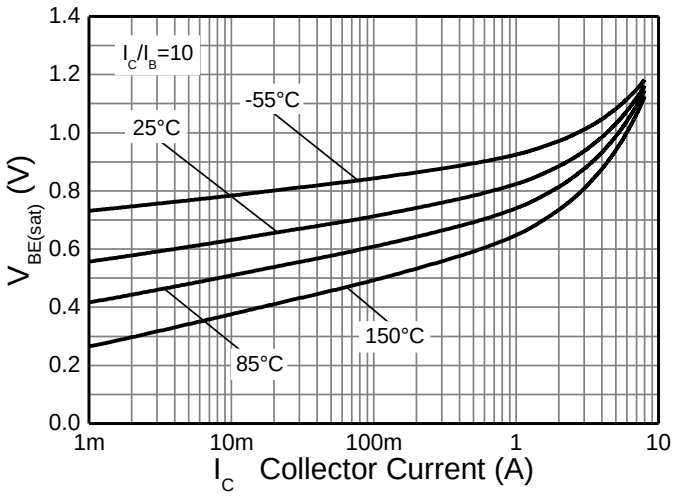
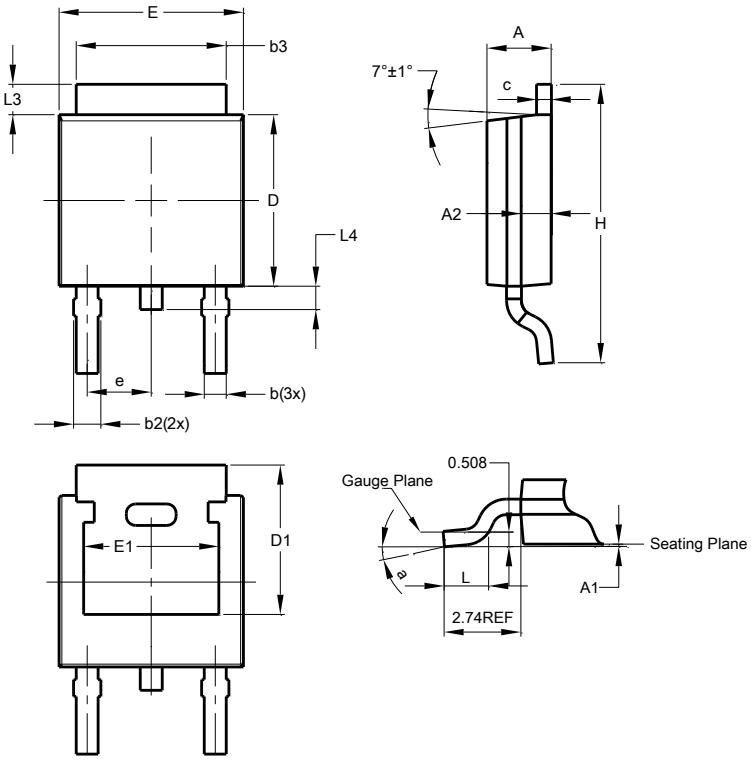


Figure 12. $V_{BE(sat)}$ v I_C

Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

TO252 (DPAK)

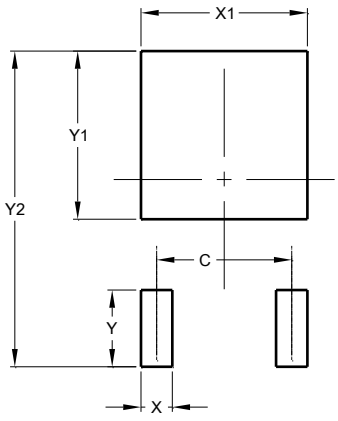


TO252 (DPAK)			
Dim	**Min**	**Max**	**Typ**
A	2.19	2.39	2.29
A1	0.00	0.13	0.08
A2	0.97	1.17	1.07
b	0.64	0.88	0.783
b2	0.76	1.14	0.95
b3	5.21	5.50	5.33
c	0.45	0.58	0.531
D	6.00	6.20	6.10
D1	5.21	--	--
e	2.286 BSC		
E	6.45	6.70	6.58
E1	4.32	--	--
H	9.40	10.41	9.91
L	1.40	1.78	1.59
L3	0.88	1.27	1.08
L4	0.64	1.02	0.83
a	0°	10°	--
All Dimensions in mm			

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

TO252 (DPAK)



Dimensions	Value (in mm)
C	4.572
X	1.060
X1	5.632
Y	2.600
Y1	5.700
Y2	10.700

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